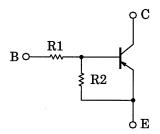
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process) (Bias Resistor built-in Transistor)

# RN2107, RN2108, RN2109

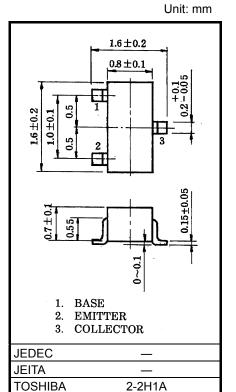
Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications

- Built-in bias resistors
- Simplified circuit design
- Fewer parts and simplified manufacturing process
- Complementary to RN1107 to RN1109

### **Equivalent Circuit and Bias Resistor Values**



Type No.	R1 (kΩ)	R2 (kΩ)
RN2107	10	47
RN2108	22	47
RN2109	47	22



Weight: 2.4 mg (typ.)

### Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic	Symbol	Rating	Unit		
Collector-base voltage	RN2107 to 2109	$V_{CBO}$	-50	V	
Collector-emitter voltage	1(102107 to 2109	V <sub>CEO</sub>	-50	V	
	RN2107		-6		
Emitter-base voltage	RN2108 V <sub>EBO</sub>		-7	V	
			-15		
Collector current		IC	-100	mA	
Collector power dissipation	RN2107 to 2109	P <sub>C*</sub>	100	mW	
Junction temperature	KN2107 t0 2109	Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	−55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

\*: Total rating

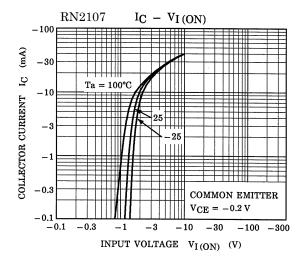
Start of commercial production 1990-12

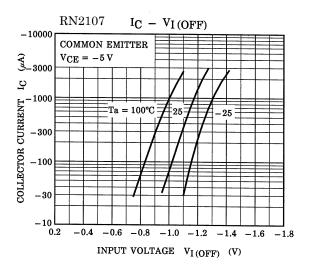


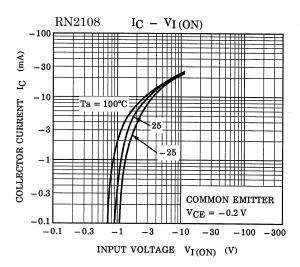
## Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

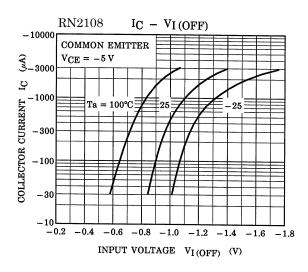
Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off	RN2107 to 2109	I <sub>CBO</sub>		$V_{CB} = -50 \text{ V}, I_{E} = 0$	_	_	-100	nA
current	14142107 10 2109	I <sub>CEO</sub>	_	$V_{CE} = -50 \text{ V}, I_B = 0$	_	_	-500	nA
	RN2107			$V_{EB} = -6 \text{ V}, I_C = 0$	-0.081	_	-0.15	
Emitter cut-off current	RN2108	I <sub>EBO</sub>	_	$V_{EB} = -7 \text{ V}, I_{C} = 0$	-0.078	_	-0.145	mA
	RN2109			V <sub>EB</sub> = −15 V, I <sub>C</sub> = 0	-0.167	_	-0.311	
	RN2107				80	_	_	
DC current gain	RN2108	$h_{FE}$	_	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$	80	_	_	_
	RN2109				70	_	_	
Collector-emitter saturation voltage	RN2107 to 2109	V <sub>CE</sub> (sat)	_	$I_C = -5 \text{ mA}, I_B = -0.25 \text{ mA}$	_	-0.1	-0.3	٧
	RN2107				-0.7	_	-1.8	
Input voltage (ON)	RN2108	V <sub>I (ON)</sub>	_	$V_{CE} = -0.2 \text{ V}, I_{C} = -5 \text{ mA}$	-1.0	_	-2.6	V
	RN2109				-2.2	_	-5.8	
	RN2107				-0.5	_	-1.0	
Input voltage (OFF)	RN2108	V <sub>I (OFF)</sub>	_	$V_{CE} = -5 \text{ V}, I_{C} = -0.1 \text{ mA}$	-0.6	_	-1.16	V
	RN2109				-1.5	_	-2.6	
Transition frequency	RN2107 to 2109	f <sub>T</sub>	_	$V_{CE} = -10 \text{ V}, I_{C} = -5 \text{ mA}$	_	200	_	MHz
Collector Output capacitance	RN2107 to 2109	$C_{ob}$	_	$V_{CB} = -10 \text{ V}, I_E = 0,$ f = 1 MHz	_	3	6	pF
	RN2107				7	10	13	
Input resistor	RN2108	R1	_	_	15.4	22	28.6	kΩ
	RN2109				32.9	47	61.1	
	RN2107				0.191	0.213	0.232	
Resistor ratio	RN2108	R1/R2	_	_	0.421	0.468	0.515	_
	RN2109				1.92	2.14	2.35	

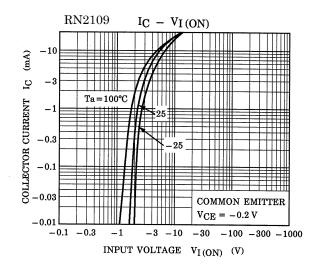
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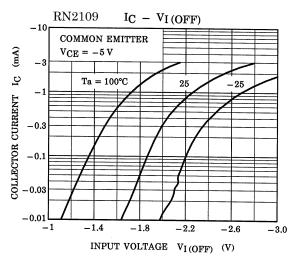


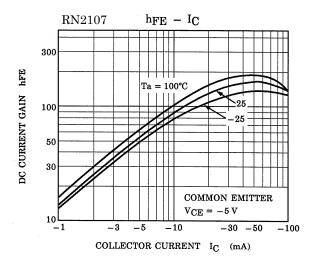


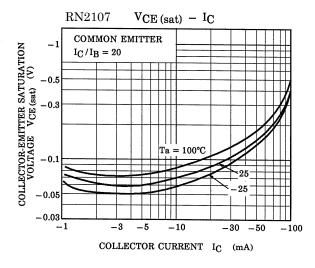


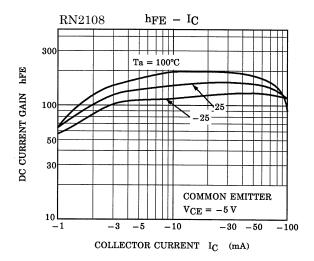


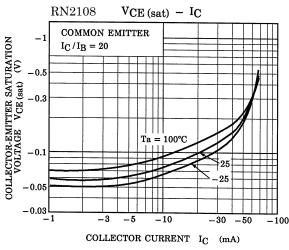


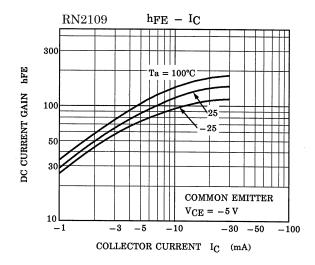


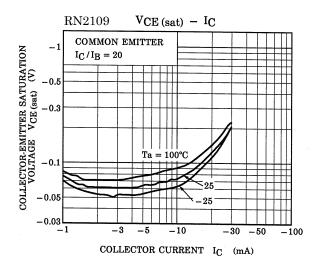












Type Name	Marking
RN2107	Type Name Y H
RN2108	Type Name
RN2109	Type Name Y J

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